

Features

- Frequency : 10, 19.2, 20, 25, 30.72
40, 48MHz
- SMD type package
- Supply voltage : 3.3V
- CMOS output
- Frequency stability over temperature :
±10ppb over -40°C ~ +85°C
- External dimensions (mm)
L : 9.5 x W : 7.3 x H : 5.5
- RoHS compliant & Pb free

Applications

- Small cell, Base station
- OTN, PTN, Switch, Router
- Precise timing & synchronization
network (IEEE1588, Sync.E)
- Enterprise networking
- Smart grid
- Test and measurement equipment

Electrical Characteristics

Item		QTO107	Conditions
Nominal Frequency (F_0)		10 MHz	
Supply Voltage (V_{DD})		3.3 V	Note [4]
Current Consumption (I_{DD})	During warm up	550 mA Typ.	Ambient temperature at 25°C
	At steady state	170 mA Max.	
Initial Frequency Accuracy		±500 ppb Max.	Note [1]
Warm-up Time		3 minutes Max.	Note [2]
Reflow Shift		±1 ppm Max.	After 1 hour recovery at 25°C
Operating Temperature Range (T_{OTR})		-40°C ~ +85°C	
Frequency Stability	vs Temperature	±10ppb , ±15ppb , ±20ppb	Note [3]
	vs Supply Voltage	±10ppb Typ.	Note [4]
	vs Load	±10ppb Typ.	Note [5]
Frequency Slope (in still air)		±1 ppb/°C Max.	Note [6]
Output Load		15 pF	
Output Type		CMOS	
Output Voltage High (V_{OH})		90% V_{DD} Min.	
Output Voltage Low (V_{OL})		10% V_{DD} Min.	
Duty Cycle		45% ~ 55%	
Rise & Fall Time (T_r / T_f)		4 ns Max.	

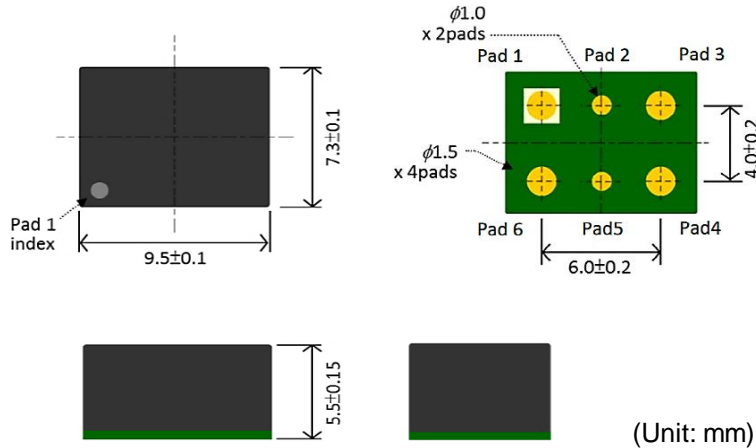
Electrical Characteristics (Continued)

Item		QTO107	Conditions
Phase Noise (@10MHz Carrier)	at 1Hz offset	-80 dBc/Hz Typ.	Ambient temperature at 25°C Note [7]
	at 10Hz offset	-112 dBc/Hz Typ.	
	at 100Hz offset	-135 dBc/Hz Typ.	
	at 1kHz offset	-150 dBc/Hz Typ.	
	at 10kHz offset	-158 dBc/Hz Typ.	
	at 100kHz offset	-158 dBc/Hz Typ.	
	at 1MHz offset	-160 dBc/Hz Typ.	
Allan Deviation (Tau = 1.0s)		5.0* e-11 Typ.	Ambient temperature at 25°C
Aging (F _{aging})	Daily	±1.0 ppb Max.	After 60 days of operation
	1st year	±0.5 ppm Max.	
	10 years	±2.0 ppm Max.	
Free-run Accuracy		±4.6 ppm Max.	Note [8]
Storage Temperature Range (T _{STR})		-55°C ~ +125°C	

Notes:

- [1] At time of shipment, refer to nominal frequency at 25°C±2°C.
- [2] Time needed for frequency to be within ±20ppb refer to frequency after 1 hour, at 25°C.
- [3] Within operating temperature range, refer to (Fmax + Fmin)/2.
- [4] F0 < 40MHz, V_{DD} variation ±5%, refer to frequency at V_{DD} = 3.3V.
F0 ≥ 40MHz, V_{DD} variation ±2%, refer to frequency at V_{DD} = 3.3V.
- [5] Load variation ±5%, refer to frequency at Load = 15pF.
- [6] Temperature ramping rate 0.5°C/minute max.
- [7] Phase noise degrades with increasing output frequency.
- [8] Including all causes in 20years, refer to nominal frequency at 25°C±2°C.

Dimensions

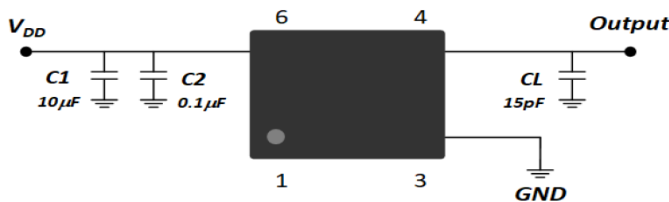


Pin function

Pin	Function
1	No Connection
2	No Connection
3	GND
4	Output
5	No Connection
6	V _{DD}

(Unit: mm)

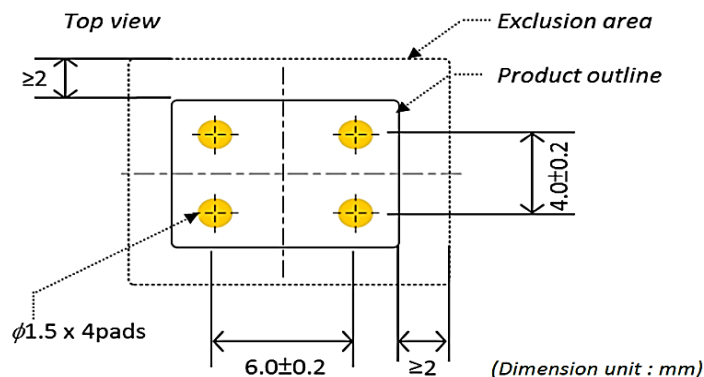
Testing Circuit



External components

C1	AC noise bypass for V _{DD}
C2	AC noise bypass for V _{DD}
CL	Load capacitance
Note: Bypass capacitor should be placed	

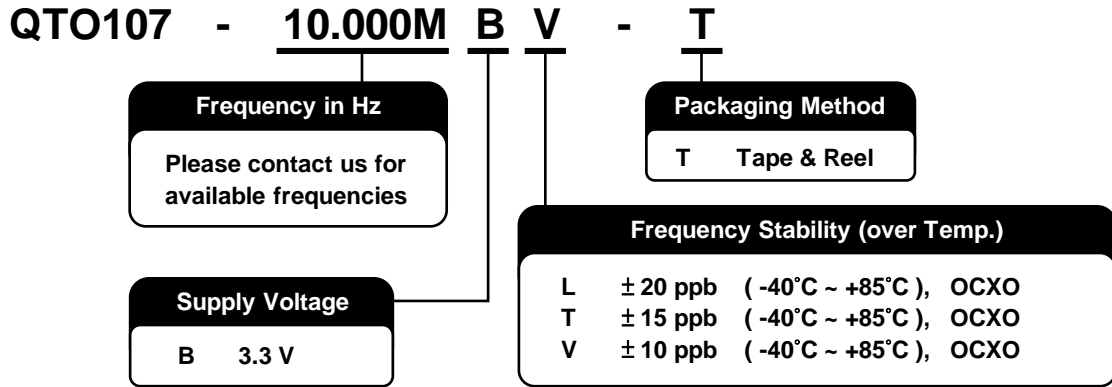
Recommended Pad Layout



Notes:

- (1) Recommended exclusion area in any copper plane to isolate the OCXO from the underlying ground or power planes to reduce thermal loss.
- (2) To further minimize the thermal loss, it is also recommended that the trace connecting to the pads should not connect to any layer inside the exclusion area.
- (3) For the same reason, it is recommended to preserve the exclusion area larger than the product size of 2mm in both of length and width.

Ordering Information



Reflow Profile (Pb-free)

